

Features

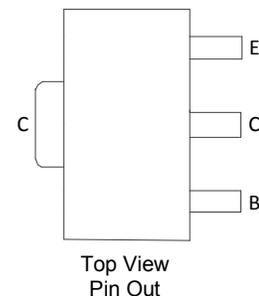
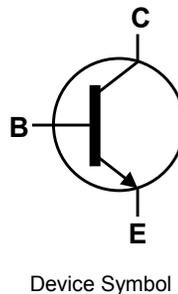
- $BV_{CEO} > 12V$
- Low Saturation Voltage $V_{CE(sat)} < 38mV @ 1A$
- $I_C = 6.5A$ High Continuous Current
- $P_D = 2.4W$ Power Dissipation
- $R_{sat} = 25m\Omega$ for a Low Equivalent On-Resistance
- Complementary part number: ZXTP25012EZ
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.05 grams (Approximate)

Application

- LED driving
- Motor driving
- Boost converters
- Royer converters
- Camera strobe
- MOSFET gate drivers

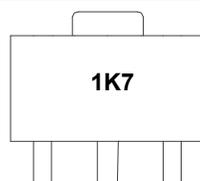


Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN25012EZTA	Standard	1K7	7	12	1,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



1K7 = Product Type Marking Code

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

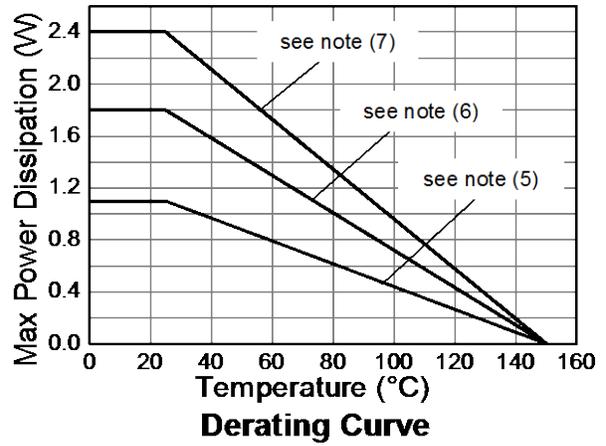
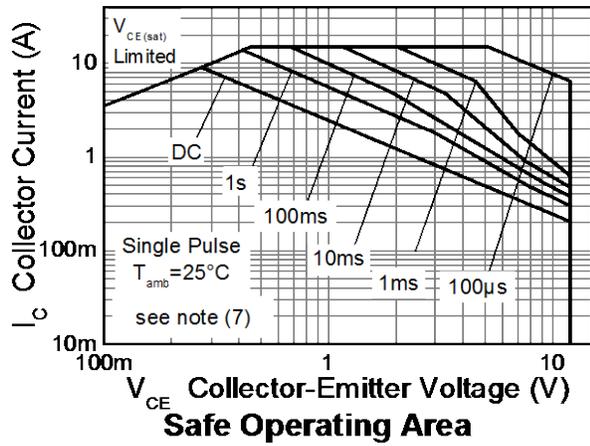
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	20	V
Collector-Emitter Voltage	V_{CEO}	12	V
Emitter-Collector Voltage (reverse blocking)	V_{ECX}	6	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	6.5	A
Peak Pulse Collector Current (single pulse)	I_{CM}	15	A
Base Current	I_B	1	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

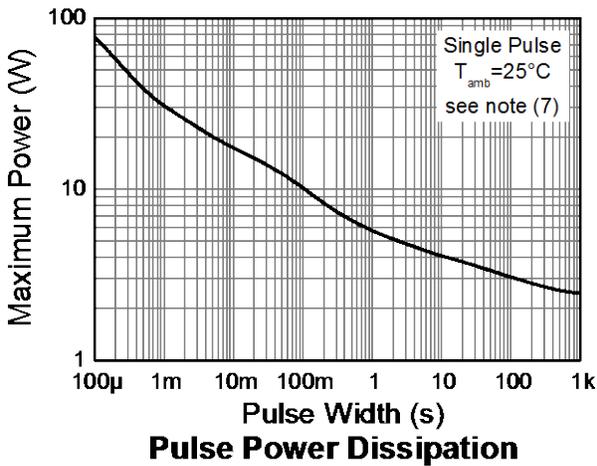
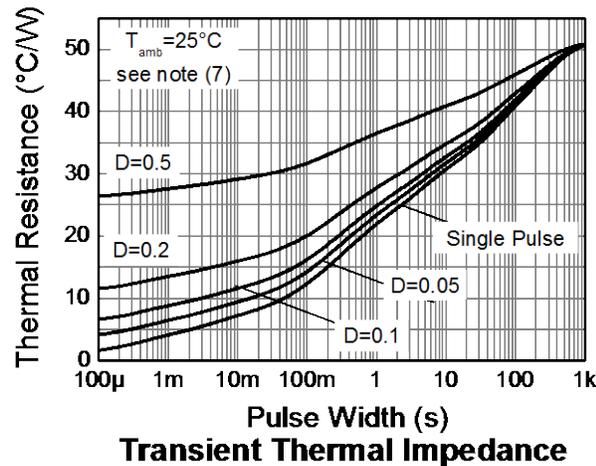
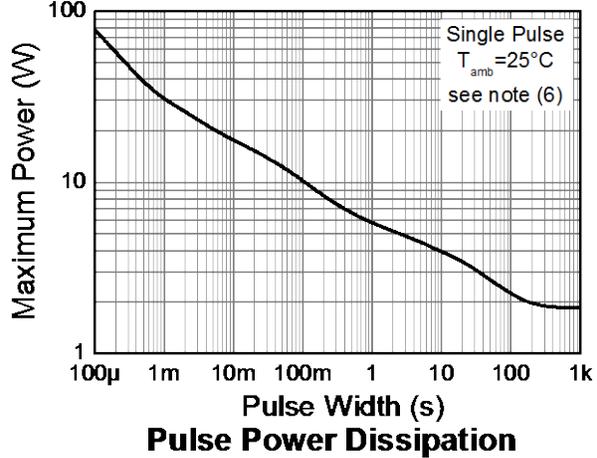
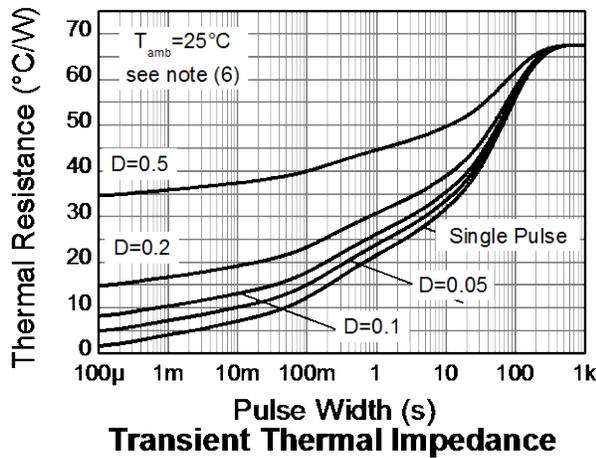
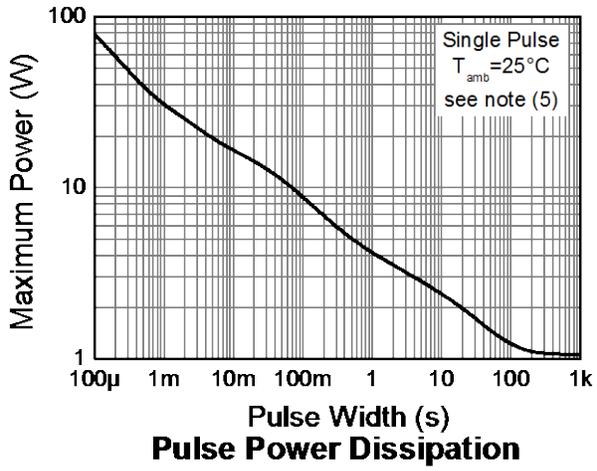
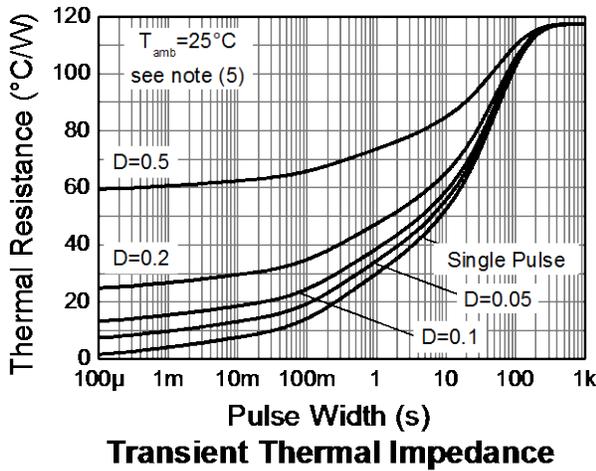
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	P_D	1.1 8.8	W mW/ $^\circ\text{C}$
Power Dissipation (Note 6) Linear Derating Factor	P_D	1.8 14.4	W mW/ $^\circ\text{C}$
Power Dissipation (Note 7) Linear Derating Factor	P_D	2.4 19.2	W mW/ $^\circ\text{C}$
Power Dissipation (Note 8) Linear Derating Factor	P_D	4.46 35.7	W mW/ $^\circ\text{C}$
Power Dissipation (Note 9) Linear Derating Factor	P_D	19.2 153	W mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	117	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	68	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	51	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient (Note 8)	$R_{\theta JA}$	28	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case (Note 9)	$R_{\theta JC}$	7.95	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.
 6. Same as note (5), except the device is mounted on 25mm x 25mm x 0.6mm single sided 1oz weight copper.
 7. Same as note (5), except the device is mounted on 50mm x 50mm x 0.6mm single sided 1oz weight copper.
 8. Same as note (5), except the device is measured at $t < 5$ seconds.
 9. Junction to case (collector tab). Typical.

Thermal Characteristics and Derating Information



Thermal Characteristics and Derating Information (cont.)

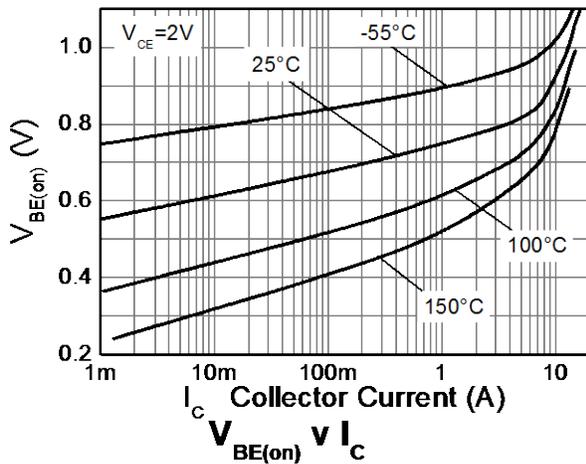
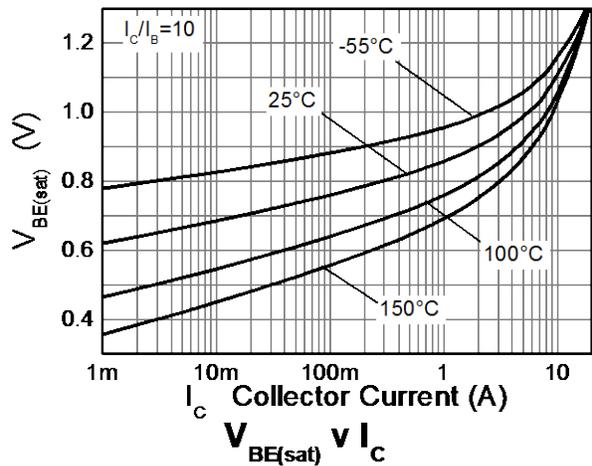
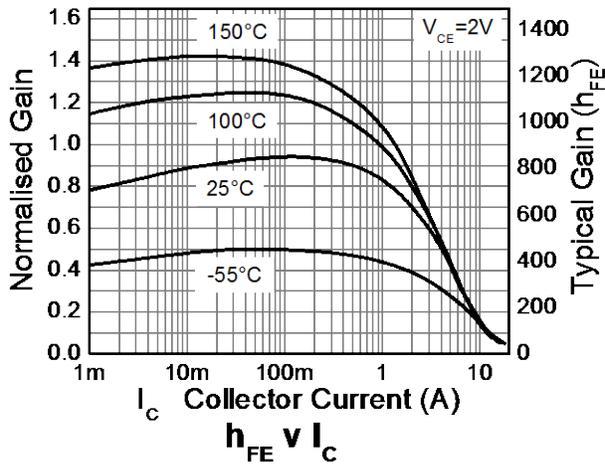
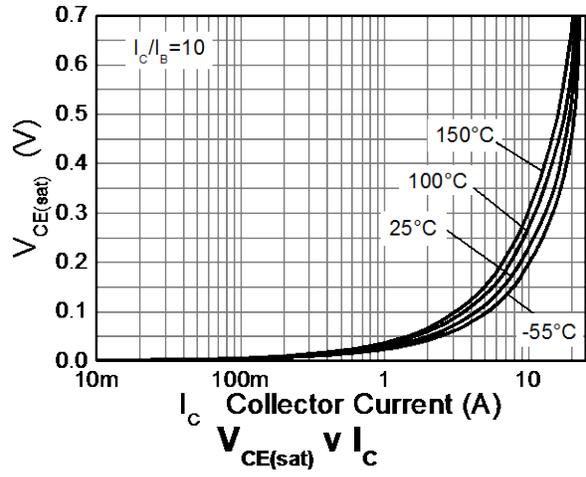
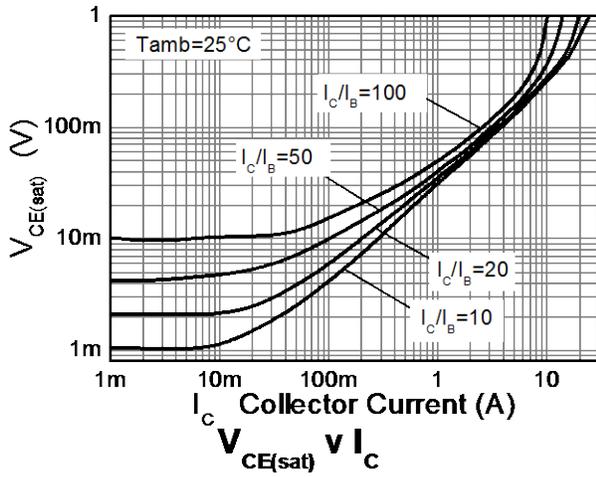


Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	20	40	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	12	17	—	V	$I_C = 10\text{mA}$
Emitter-Collector breakdown voltage (reverse blocking)	BV_{ECX}	6	8	—	V	$I_E = 100\text{mA}$, $R_{BC} < 1\text{k}\Omega$ or $0.25\text{V} > V_{BC} > -0.25\text{V}$
Emitter-Collector breakdown voltage (reverse blocking)	BV_{ECO}	4.5	5.5	—	V	$I_E = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.3	—	V	$I_E = 100\mu\text{A}$
Collector-Base Cutoff Current	I_{CBO}	—	1	50	nA μA	$V_{CB} = 20\text{V}$ $V_{CB} = 20\text{V}$, $T_A = +100^\circ\text{C}$
Collector-Emitter Cutoff Current	I_{CEX}	—	—	100	nA	$V_{CE} = 20\text{V}$, $R_{BE} < 1\text{k}\Omega$ or $-1\text{V} < V_{BE} < 0.25\text{V}$
Emitter Cutoff Current	I_{EBO}	—	1	50	nA	$V_{EB} = 5.6\text{V}$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	—	31 50 70 90 200	38 60 85 130 270	mV	$I_C = 1\text{A}$, $I_B = 100\text{mA}$ $I_C = 1\text{A}$, $I_B = 10\text{mA}$ $I_C = 2\text{A}$, $I_B = 40\text{mA}$ $I_C = 2\text{A}$, $I_B = 20\text{mA}$ $I_C = 6.5\text{A}$, $I_B = 130\text{mA}$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	—	950	1050	mV	$I_C = 6.5\text{A}$, $I_B = 130\text{mA}$
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(on)}$	—	840	950	mV	$I_C = 6.5\text{A}$, $V_{CE} = 2\text{V}$
DC Current Gain (Note 10)	h_{FE}	500 500 185 30	800 750 250 50	1500 — — —	—	$I_C = 10\text{mA}$, $V_{CE} = 2\text{V}$ $I_C = 1\text{A}$, $V_{CE} = 2\text{V}$ $I_C = 6.5\text{A}$, $V_{CE} = 2\text{V}$ $I_C = 15\text{A}$, $V_{CE} = 2\text{V}$
Transitional frequency	f_T	—	260	—	MHz	$I_C = 50\text{mA}$, $V_{CE} = 10\text{V}$, $f = 100\text{MHz}$
Input Capacitance	C_{ibo}	—	137	250	pF	$V_{EB} = 0.5\text{V}$, $f = 1\text{MHz}$
Output Capacitance	C_{obo}	—	25	35	pF	$V_{CB} = 10\text{V}$, $f = 1\text{MHz}$
Delay time	t_d	—	71	—	ns	$V_{CC} = 10\text{V}$, $I_C = 1\text{A}$, $I_{B1} = -I_{B2} = 10\text{mA}$
Rise time	t_r	—	70	—	ns	
Storage time	t_s	—	233	—	ns	
Fall time	t_f	—	72	—	ns	

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

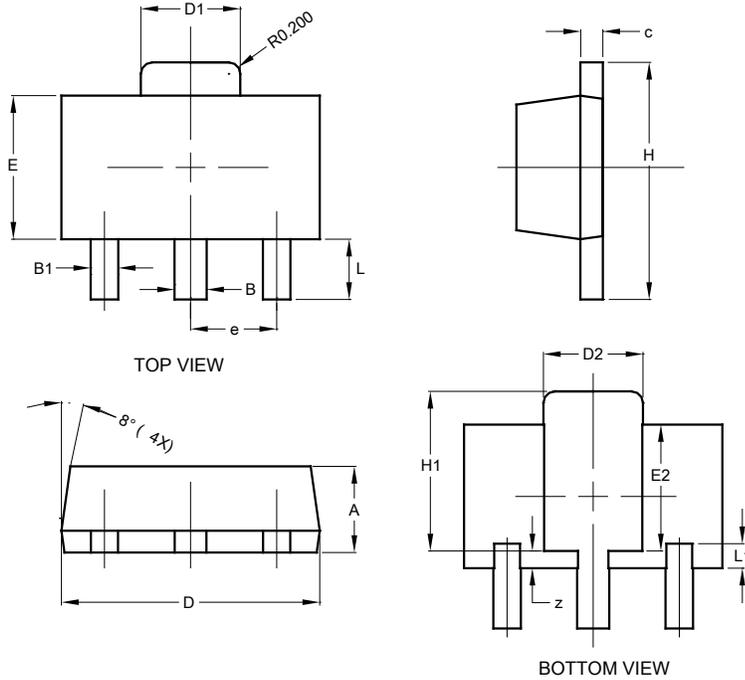
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT89

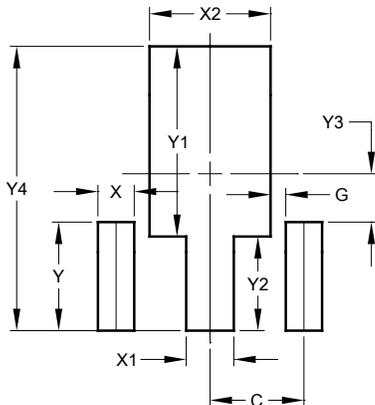


SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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